

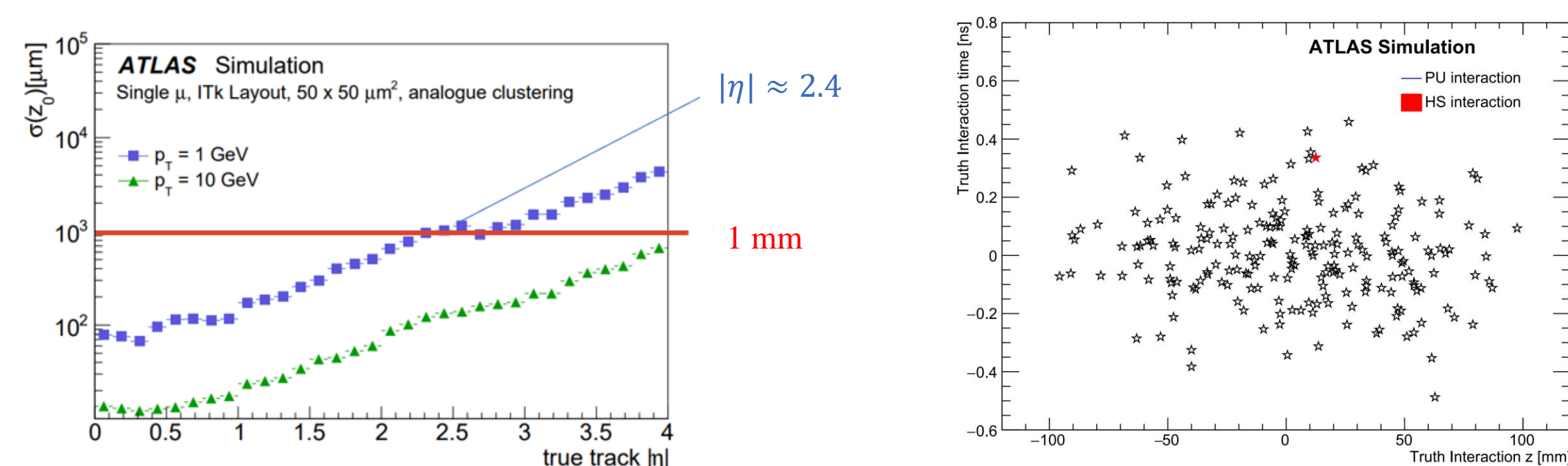
Measurement of HGTD Module Bonded with ACP technique

Aonan Wang

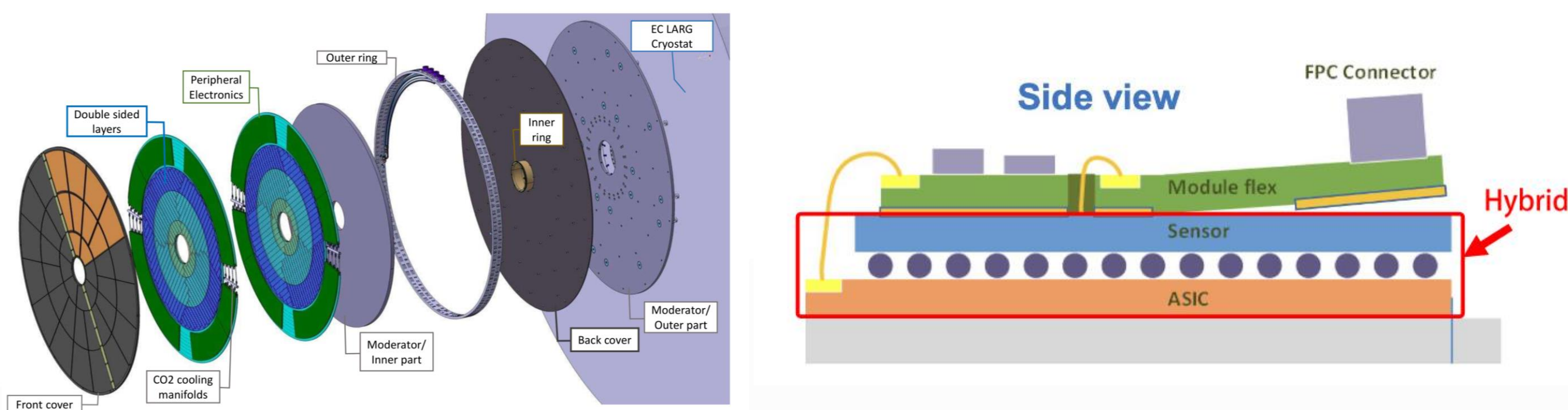
University of Science and Technology of China, Hefei 230026

High Granularity Timing Detector (HGTD)

As LHC upgraded into HL-LHC, instantaneous luminosity will reach $7.5 \times 10^{34} \text{ cm}^{-2} \text{ s}^{-1}$, which means significant increase in pile-up. A novel timing detector, HGTD, will be installed in forward region. By utilizing timing information, hard scattering vertices can be distinguished in such situation.

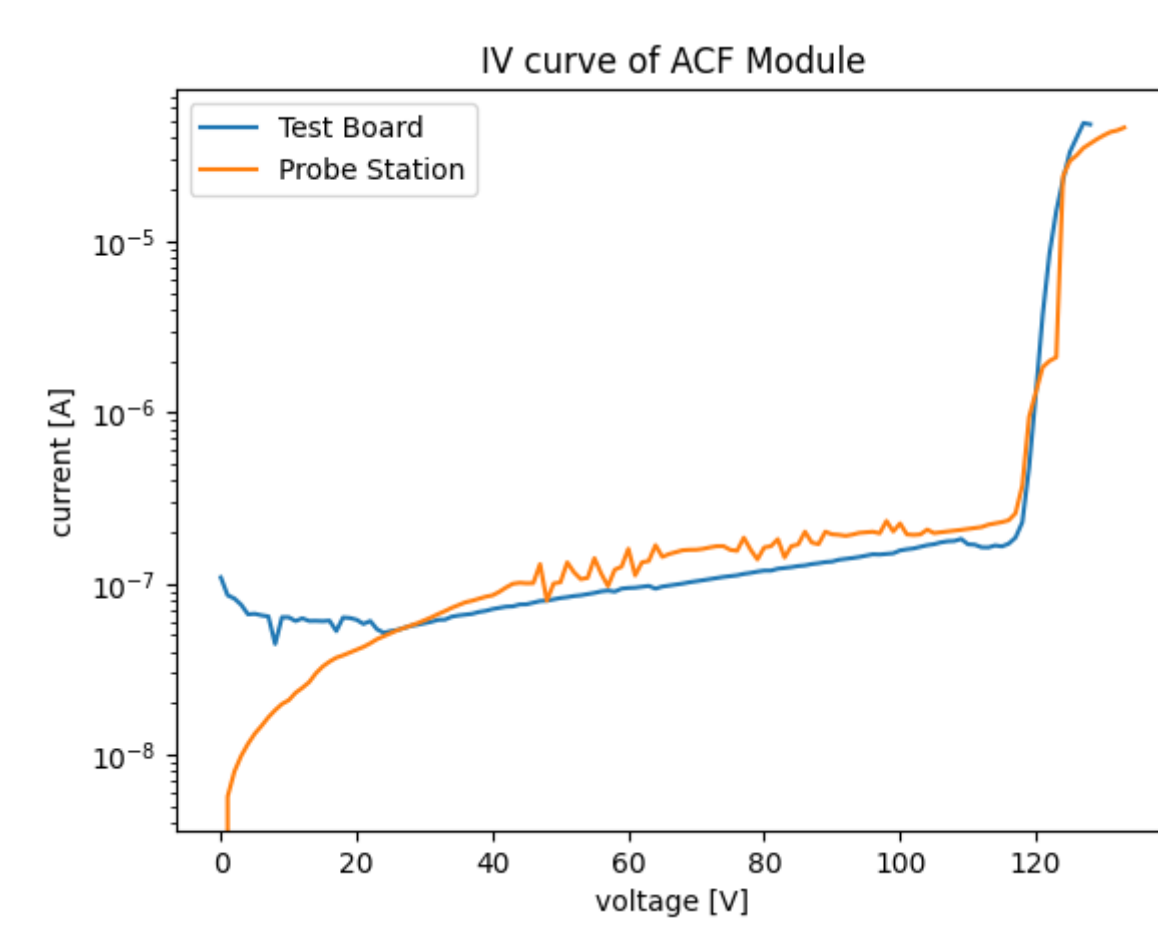
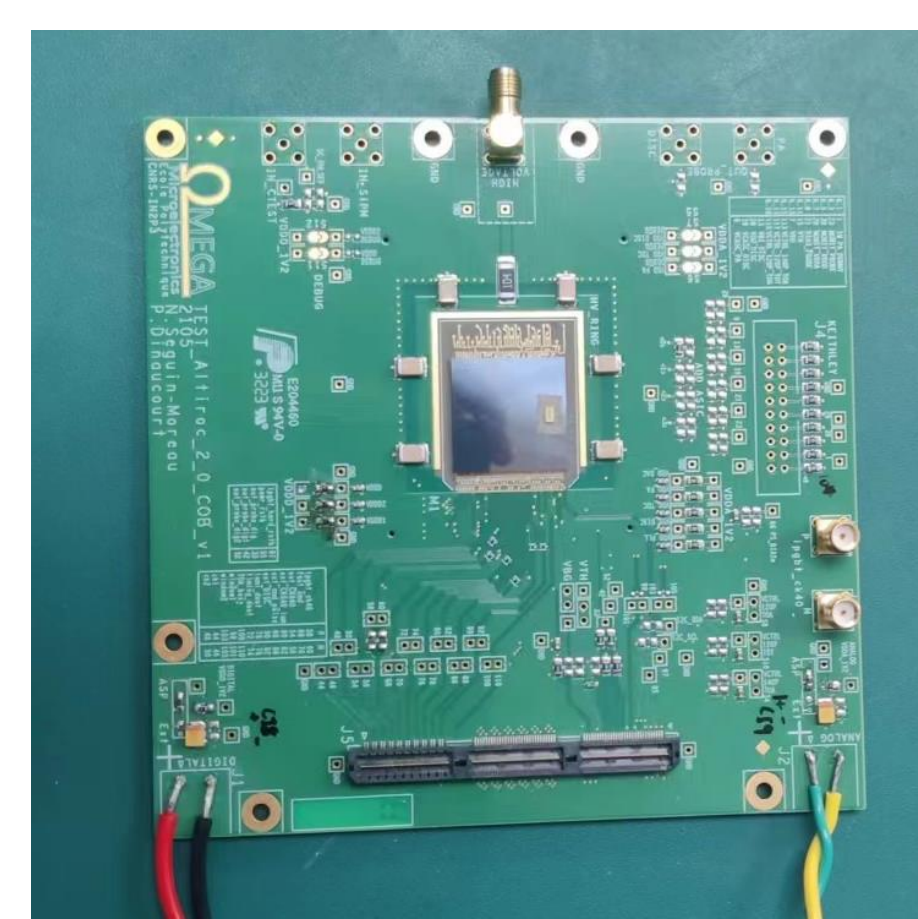


- The Low Gain Avalanche Detector (LGAD) is used as sensor for HGTD.
- Front-end Application Specific Integrated Circuit (ASIC) named ALTIROC.
- The sensor is flip-chip bonded to the ALTIROC to create a hybrid.
- Two hybrids are then glued to the Module flex PCB and wire bonded to it, forming a module.

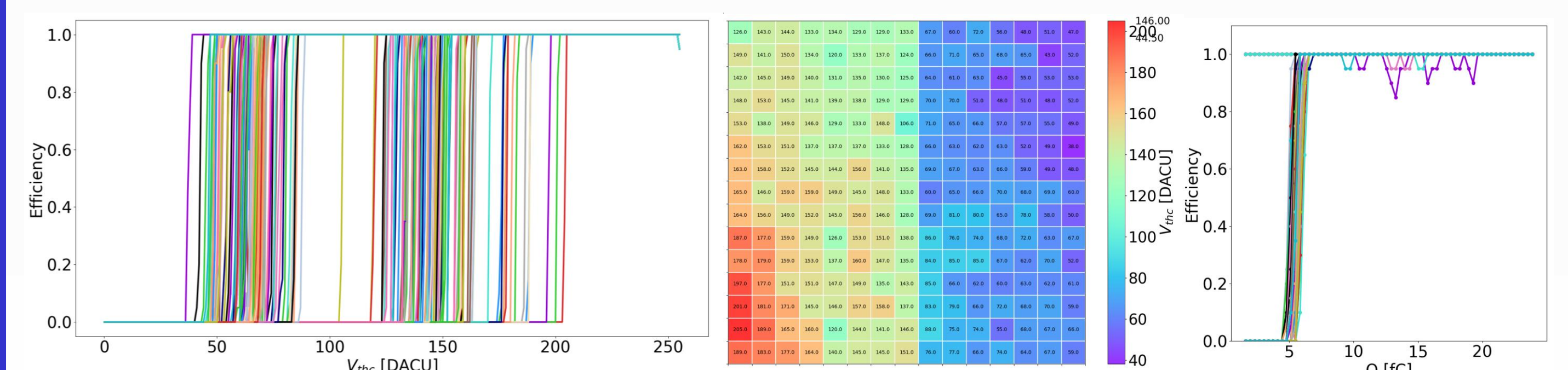


Test result for the ACP module

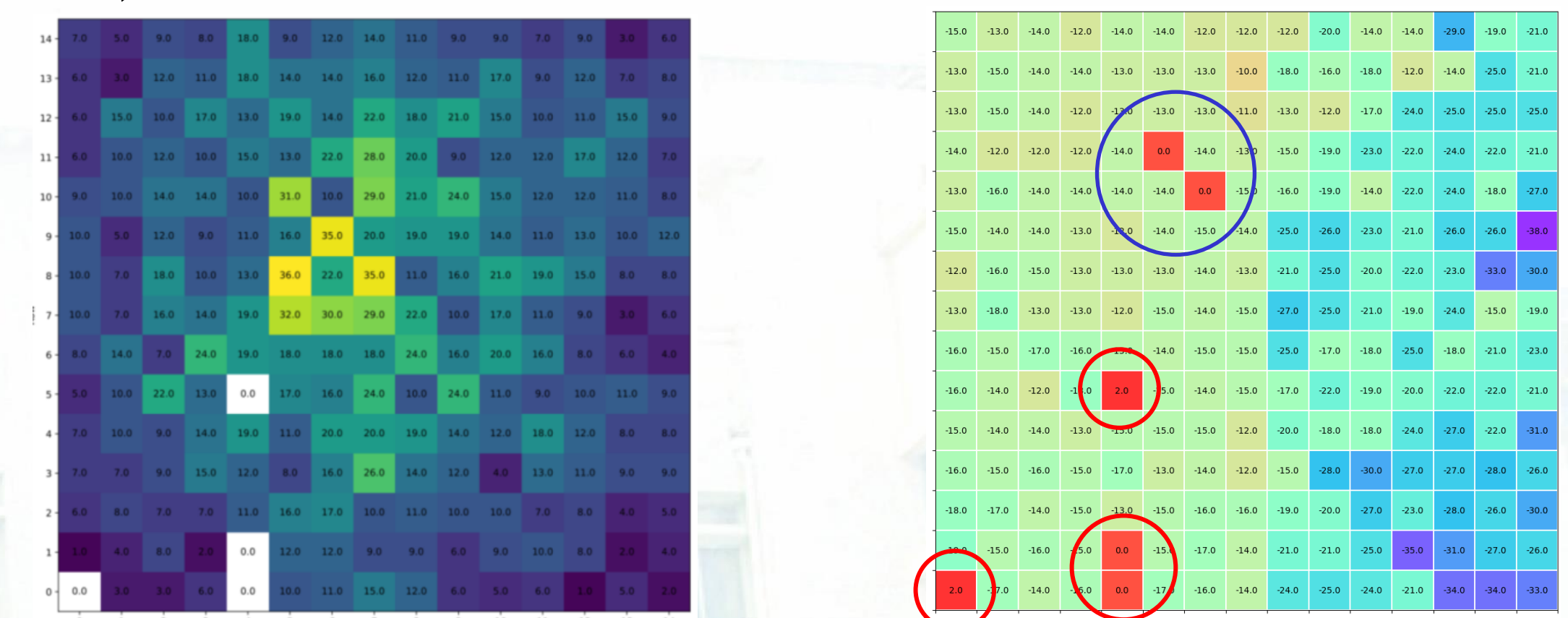
- We have received the first ACP module from UNIGE, and attach it to the test board developed by IJCLAB and perform wire bonding on it.
- For the readout, we use Interface board provided by IJCLAB and ZC706. The firmware and software in use are FADA.
- We also make a frame to support Sr-90 radioactive source for the connection between ASIC and LGAD check.



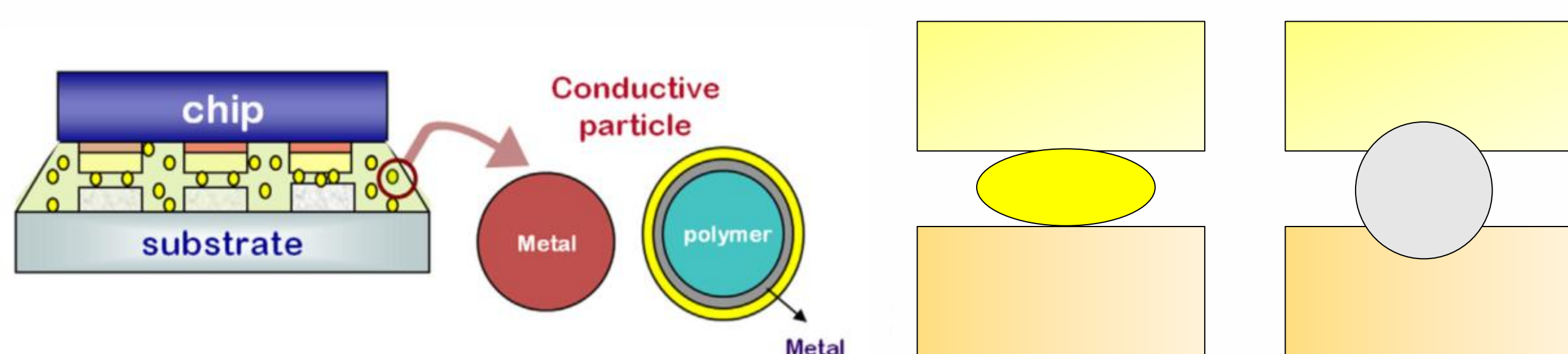
- First, we check the current (I) vs voltage (V) relationship with system set in the climate chamber, and found it is comparable with the result got on probe station.
- We tune threshold voltage per channel and use charge scan to validate obtained threshold voltage value.
- The efficiency of some channels is always one due to the failure of charge injection in two channel of ASIC.



- Electron from Sr-90 induce signal in the sensor, connected channel will output hits.
- Using different capacitance before and after bias voltage turns on, with same injected charge, the threshold of connected channel will vary with bias.
- Radioactive source shows four channels are not connected.
- A detailed investigation revealed failures in the charge injection system of two channels, and found four channels were not connected.

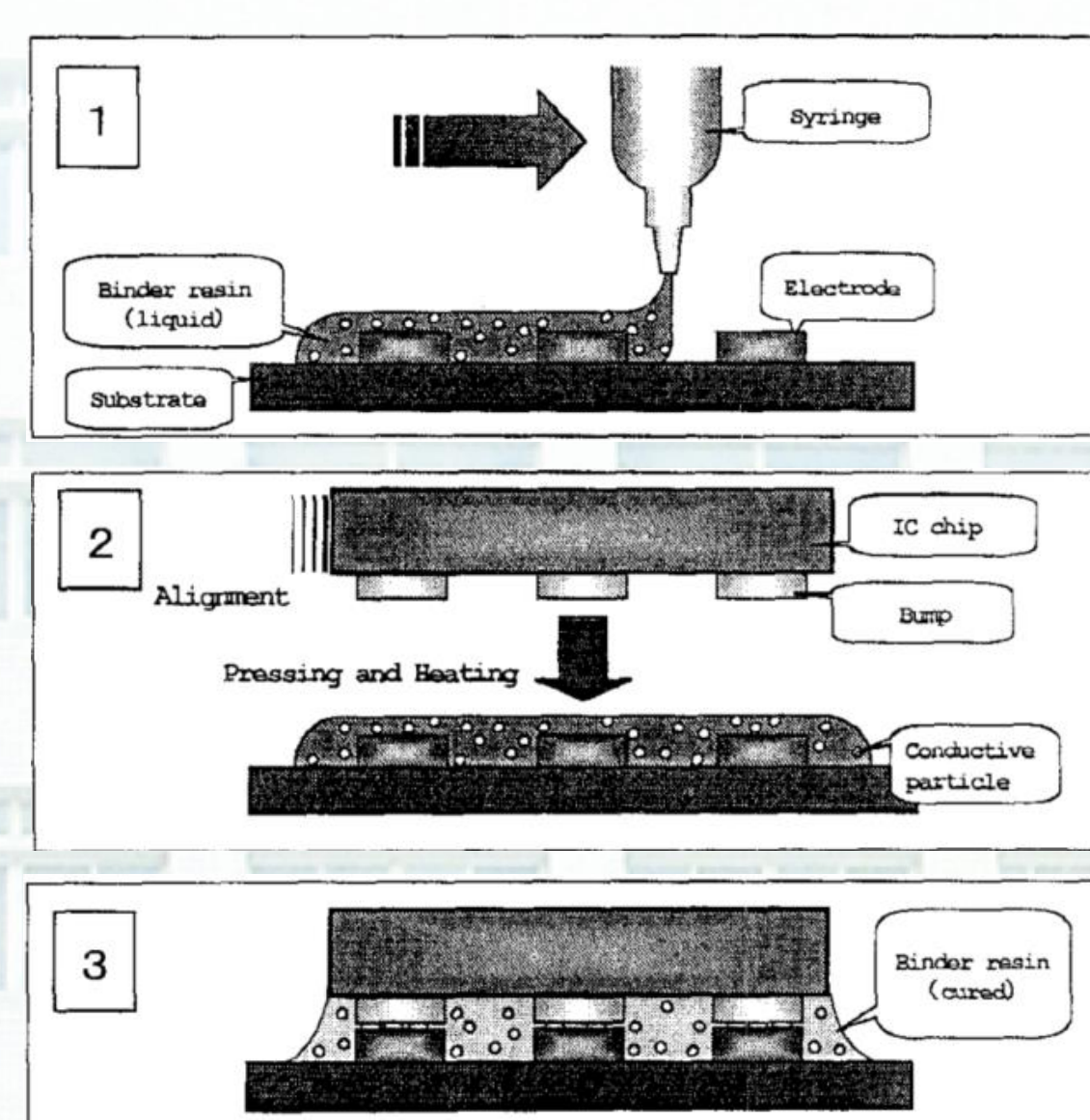


Anisotropic Conductive Paste (ACP) Technique



- The ACP is composed of conductive fine particles diffused in nonconductive resin.
- Two kinds of conductive particle can be used.
 - Metal coat resin particle and soft metal particle. Make contact through their deformation under pressure.
 - Hard metal particle (e.g. Ni) will be squeezed into electrode and make contact with it.

- Bonding process including following steps:
 - Dispense paste.
 - Apply force in Z-axis, and trape conductive particles between the bump and the corresponding pad.
 - Cure the paste with heat or other energy.
- Potential reasons for an increase of contact resistance:
 - Thermal expansion mismatch.
 - Swelling of paste.



- Key factor for ACP bonding

Curing Temperature	Pressure	Resin	Conductive particle	Bump Shape	Surface treatment
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Summary

- ACP technique provided a new method for sensor ASIC flip-chip bonding, besides the solder bump bonding.
- First HGTD ACP module has been produced by UNIGE, and wire bonded to test board at USTC.
- We have setup a test system for module to measure performance of ACP module.
- Preliminary measurement results show good reliability of ACP technique in module production.

Reference

- Kim, S.-C. and Y.-H. Kim (2013). "Review paper: Flip chip bonding with anisotropic conductive film (ACF) and nonconductive adhesive (NCA)." *Current Applied Physics* **13**: S14-S25.
- Kishimoto, Y. and K. Hanamura (1998). Anisotropic conductive paste available for flip chip. *Proceedings of 3rd International Conference on Adhesive Joining and Coating Technology in Electronics Manufacturing 1998* (Cat. No.98EX180).